

UV-A Sensor

GUVA-S12SD



Features

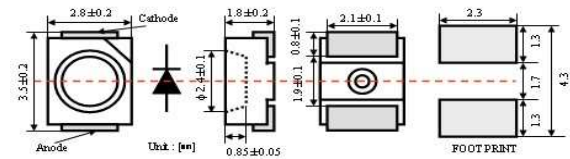
Gallium Nitride Based Material
Schottky-type Photodiode
Photovoltaic Mode Operation
Good Visible Blindness
High Responsivity & Low Dark Current



Applications

UV Index Monitoring
UV-A Lamp Monitoring

Outline Diagrams and Dimensions



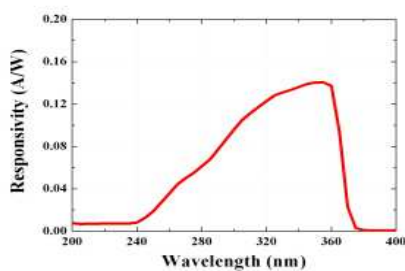
Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Unit	Remark
Storage Temperature	T_{st}	-40	90	°C	
Operating Temperature	T_{op}	-30	85	°C	
Reverse Voltage	$V_{r, max.}$		5	V	
Forward Current	$I_{f, max.}$		1	mA	
Soldering Temperature	T_{sol}		260	°C	within 10 sec.

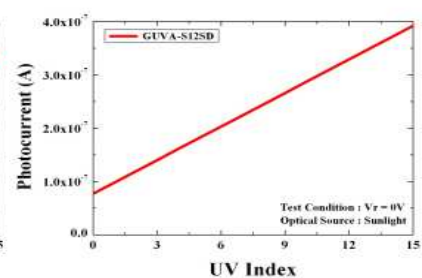
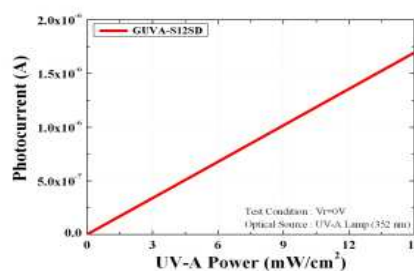
Characteristics (at 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Dark Current	I_d			1	nA	$V_r = 0.1$ V
Photo Current	I_{ph}		113		nA	UVA Lamp, 1 mW/cm ²
			26		nA	1 UVI
Temperature Coefficient	I_{tc}		0.08		%/°C	UVA Lamp
Responsivity	R		0.14		A/W	$\lambda = 350$ nm, $V_r = 0$ V
Spectral Detection Range	λ	240		370	nm	10% of R

Responsivity Curve



Photocurrent along UV Power



Caution

ESD can damage the device hence please avoid ESD.